



CHENMKO ENTERPRISE CO.,LTD

CH705DGP

Halogens free devices

SURFACE MOUNT
SCHOTTKY BARRIER DIODE

VOLTAGE 40 Volts CURRENT 0.03 Ampere

APPLICATION

- * General purpose detection
- * High speed switching

FEATURE

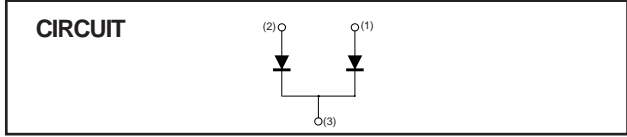
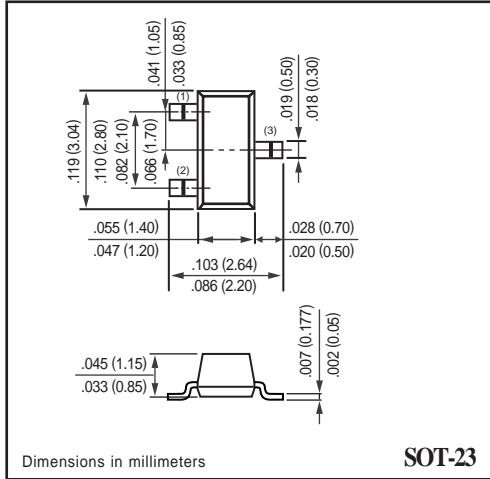
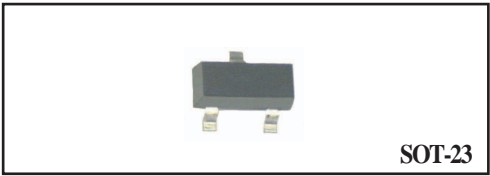
- * Small surface mounting type. (SOT-23)
- * Low VF and low IR.
- * Multiple diodes with common cathode configuration

CONSTRUCTION

- * Silicon epitaxial planar

MARKING

- * KL5



MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	CH705DGP	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	40	Volts
Maximum RMS Voltage	V _{RMS}	28	Volts
Maximum DC Blocking Voltage	V _{DC}	40	Volts
Maximum Average Forward Rectified Current	I _O	0.03	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	I _{FSM}	0.2	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	2.0	pF
Maximum Operating Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-40 to +125	°C

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH705DGP	UNITS
Maximum Instantaneous Forward Voltage at I _F = 1mA	V _F	0.37	Volts
Maximum Average Reverse Current at V _R = 10V	I _R	1.0	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 1.0 volts.
2. ESD sensitive product handling required.

RATING CHARACTERISTIC CURVES (CH705DGP)

FIG. 1 - FORWARD CHARACTERISTICS

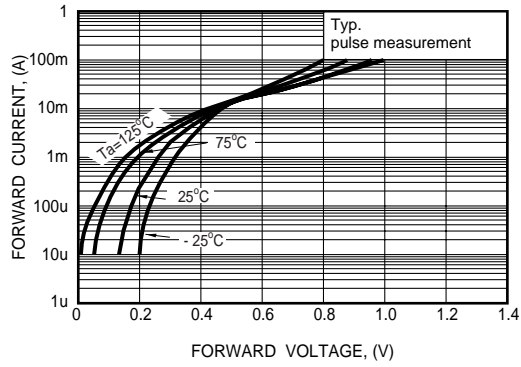


FIG. 2 - REVERSE CHARACTERISTICS

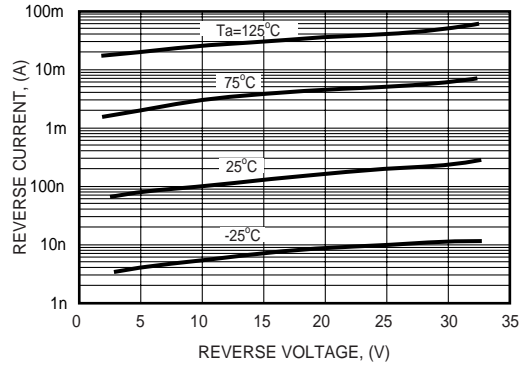


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

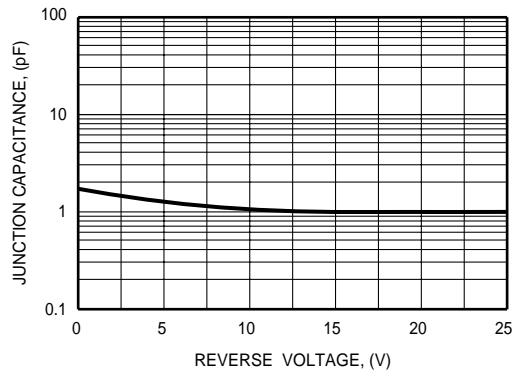


FIG. 4 - REVERSE RECOVERY TIME CHARACTERISTICS

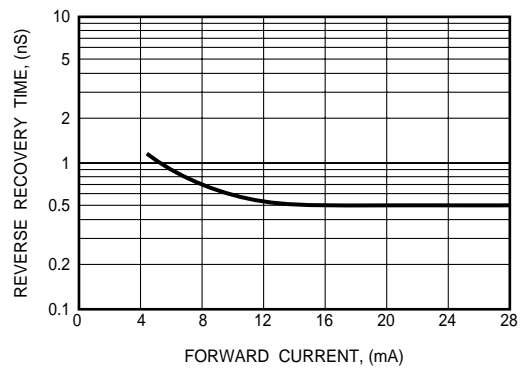


FIG. 5 - TYPICAL FORWARD CURRENT DERAING CURVE

